

MOS FIELD EFFECT TRANSISTOR

2SK1960

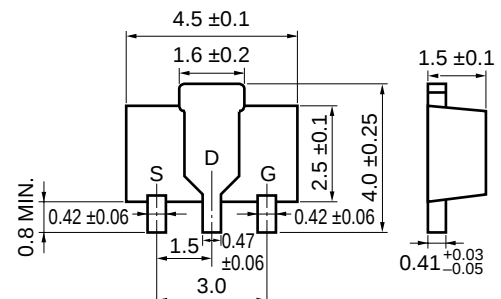
N-CHANNEL MOS FET FOR HIGH-SPEED SWITCHING

The 2SK1960 is an N-channel vertical MOSFET. Because it can be driven by a voltage as low as 1.5 V and it is not necessary to consider a drive current, this FET is ideal as an actuator for low-current portable systems such as headphone stereos and video cameras.

FEATURES

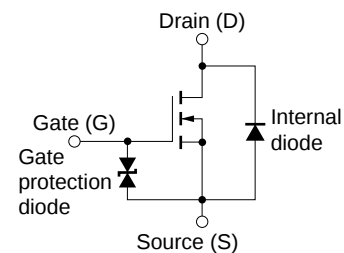
- Gate can be driven by 1.5 V
- Low ON resistance
 $R_{DS(on)} = 0.8 \Omega$ MAX. @ $V_{GS} = 1.5 \text{ V}$, $I_D = 0.1 \text{ A}$
 $R_{DS(on)} = 0.2 \Omega$ MAX. @ $V_{GS} = 4.0 \text{ V}$, $I_D = 1.5 \text{ A}$

PACKAGE DIMENSIONS (in mm)



Marking: NR

EQUIVALENT CIRCUIT



PIN CONNECTIONS

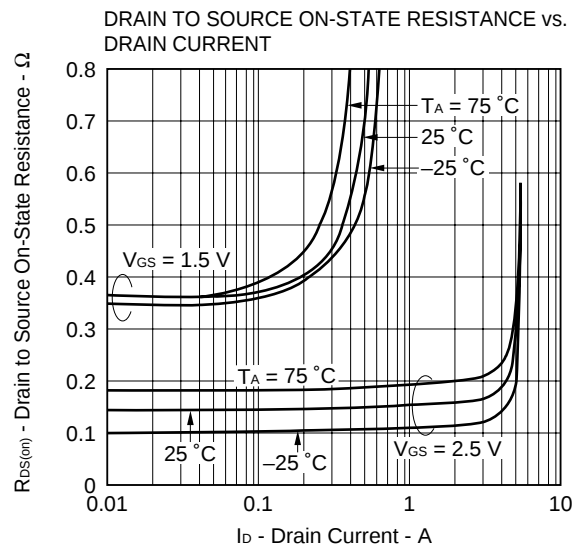
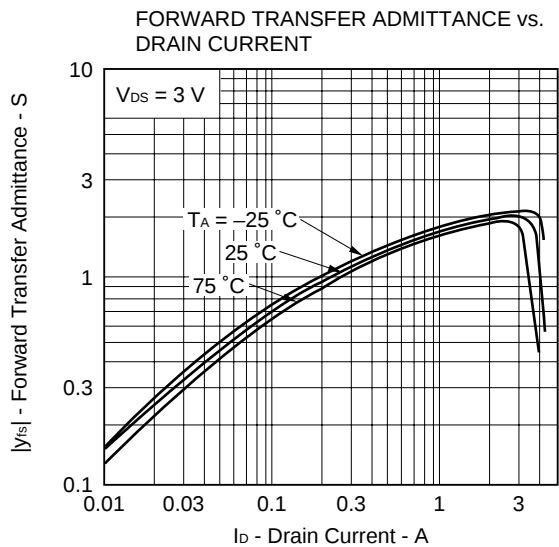
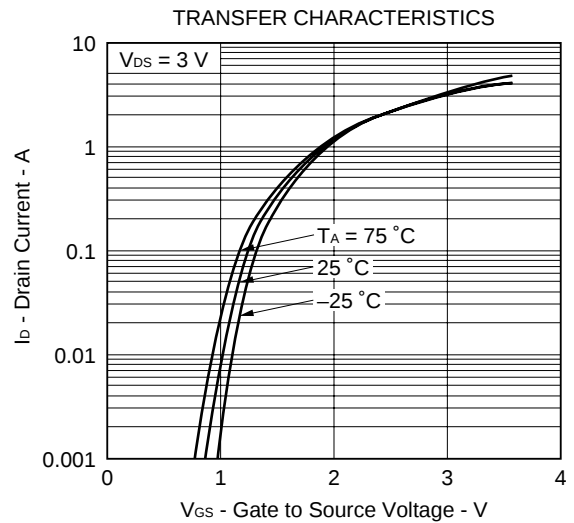
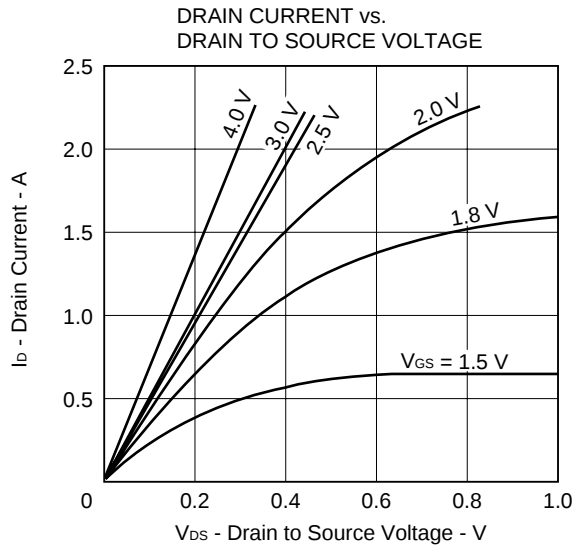
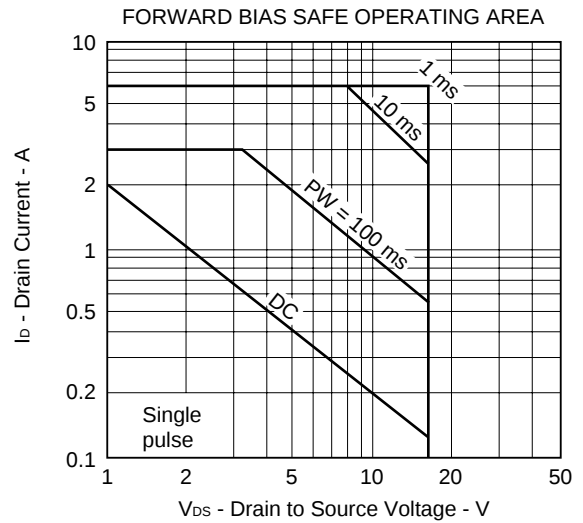
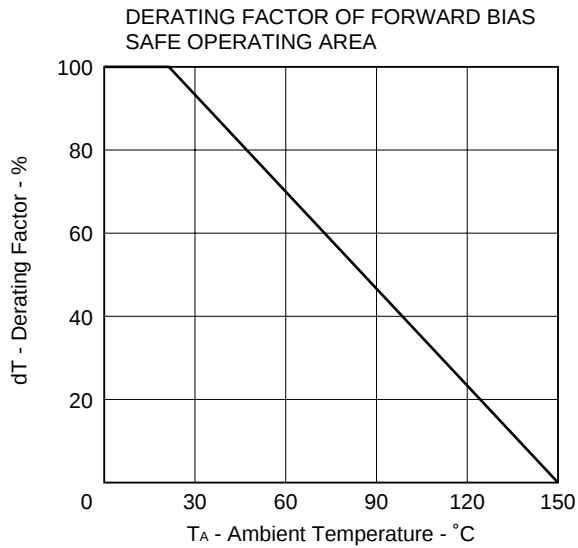
S: Source
D: Drain
G: Gate

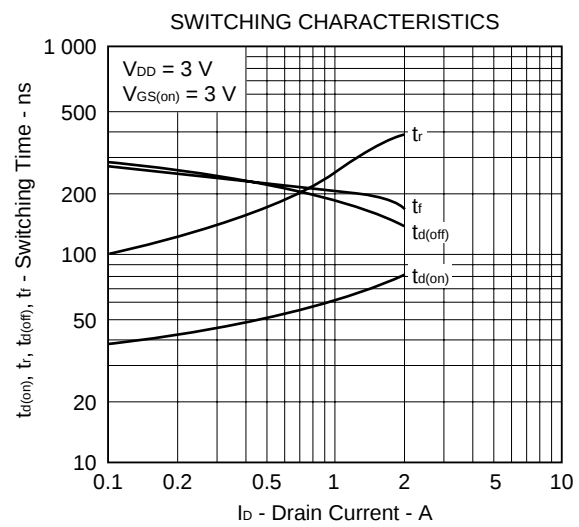
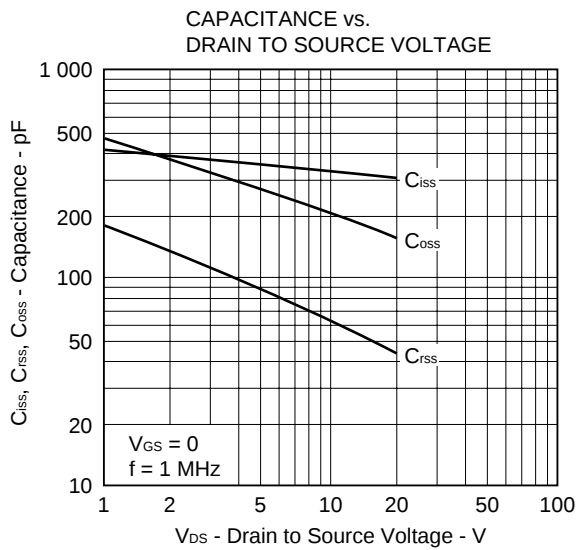
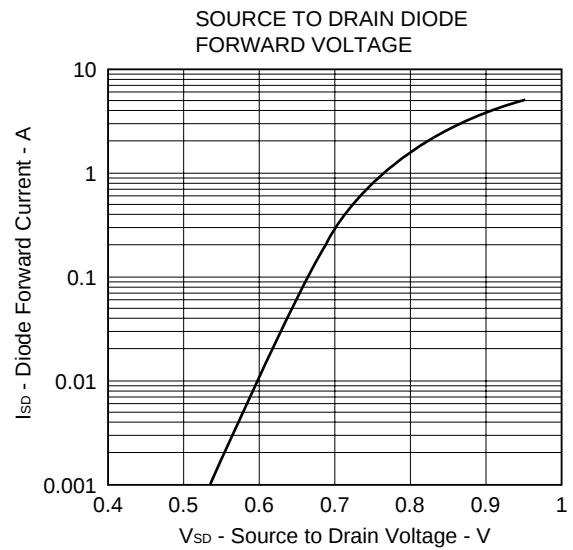
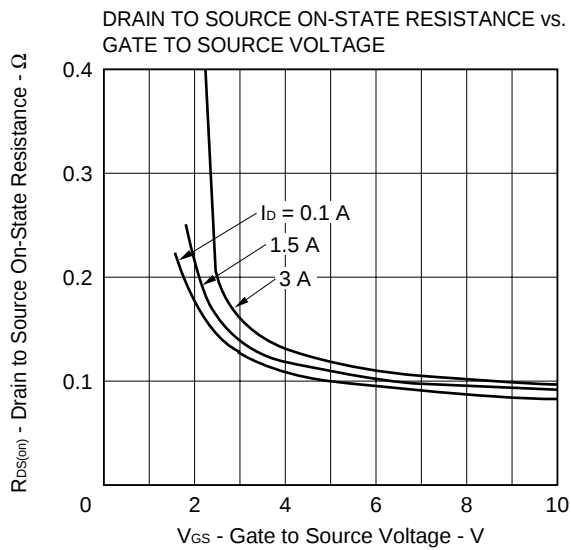
ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

PARAMETER	SYMBOL	TEST CONDITIONS	RATING	UNIT
Drain to Source Voltage	V_{DS}	$V_{GS} = 0$	16	V
Gate to Source Voltage	V_{GS}	$V_{DS} = 0$	± 7.0	V
Drain Current (DC)	$I_{D(PC)}$		± 3.0	A
Drain Current (Pulse)	$I_{D(pulse)}$	$PW \leq 10 \text{ ms}$, duty cycle $\leq 50 \%$	± 6.0	A
Total Power Dissipation	P_T	16 cm ² × 0.7 mm ceramic substrate used	2.0	W
Channel Temperature	T_{ch}		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain Cut-Off Current	I _{DSS}	V _{DS} = 16 V, V _{GS} = 0			1.0	μA
Gate Leakage Current	I _{GSS}	V _{GS} = ±7.0 V, V _{DS} = 0			±3.0	μA
Gate Cut-Off Voltage	V _{GS(off)}	V _{DS} = 3 V, I _D = 1 mA	0.5	0.8	1.1	V
Forward Transfer Admittance	y _{fs}	V _{DS} = 3 V, I _D = 1.5 A	2.0			S
Drain to Source On-State Resistance	R _{DS(on)1}	V _{GS} = 1.5 V, I _D = 0.1 A		0.35	0.8	Ω
Drain to Source On-State Resistance	R _{DS(on)2}	V _{GS} = 2.5 V, I _D = 1.5 A		0.17	0.3	Ω
Drain to Source On-State Resistance	R _{DS(on)3}	V _{GS} = 4.0 V, I _D = 1.5 A		0.12	0.2	Ω
Input Capacitance	C _{iss}	V _{DS} = 3 V, V _{GS} = 0, f = 1.0 MHz		370		pF
Output Capacitance	C _{oss}			320		pF
Reverse Transfer Capacitance	C _{rss}			115		pF
Turn-ON Delay Time	t _{d(on)}	V _{DD} = 3 V, I _D = 1.5 A, V _{GS(on)} = 3 V, R _G = 10 Ω, R _L = 2 Ω		70		ns
Rise Time	t _r			200		ns
Turn-OFF Delay Time	t _{d(off)}			150		ns
Fall Time	t _f			200		ns

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)



REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system	TEI-1202
Quality grade on NEC semiconductor devices	IEI-1209
Semiconductor device mounting technology manual	C10535E
Guide to quality assurance for semiconductor devices	MEI-1202
Semiconductor selection guide	X10679E

[MEMO]

No part of this document may be copied or reproduced in any form or by any means without the prior written consent of NEC Corporation. NEC Corporation assumes no responsibility for any errors which may appear in this document.

NEC Corporation does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from use of a device described herein or any other liability arising from use of such device. No license, either express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Corporation or others.

While NEC Corporation has been making continuous effort to enhance the reliability of its semiconductor devices, the possibility of defects cannot be eliminated entirely. To minimize risks of damage or injury to persons or property arising from a defect in an NEC semiconductor device, customer must incorporate sufficient safety measures in its design, such as redundancy, fire-containment, and anti-failure features.

NEC devices are classified into the following three quality grades:

“Standard”, “Special”, and “Specific”. The Specific quality grade applies only to devices developed based on a customer designated “quality assurance program” for a specific application. The recommended applications of a device depend on its quality grade, as indicated below. Customers must check the quality grade of each device before using it in a particular application.

Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

The quality grade of NEC devices in “Standard” unless otherwise specified in NEC's Data Sheets or Data Books. If customers intend to use NEC devices for applications other than those specified for Standard quality grade, they should contact NEC Sales Representative in advance.

Anti-radioactive design is not implemented in this product.